

# 2N5401

# **MMBT5401**





# **PNP General Purpose Amplifier**

This device is designed as a general purpose amplifier and switch for applications requiring high voltages.

### **Absolute Maximum Ratings\***

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CEO}$	Collector-Emitter Voltage	150	V
V <sub>CBO</sub>	Collector-Base Voltage	160	V
V <sub>EBO</sub>	Emitter-Base Voltage	5.0	V
I <sub>C</sub>	Collector Current - Continuous	600	mA
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
  2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.
- 3) All voltages (V) and currents (A) are negative polarity for PNP transistors.

### **Thermal Characteristics**

TA = 25°C unless otherwise noted

Symbol	Characteristic	М	Units	
		2N5401	*MMBT5401	
P <sub>D</sub>	Total Device Dissipation	625	350	mW
	Derate above 25°C	5.0	2.8	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	°C/W

<sup>\*</sup>Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

## **PNP General Purpose Amplifier**

(continued)

### **Electrical Characteristics**

TA = 25°C unless otherwise noted

Symbol	Parameter Test Conditions		Min	Max	Units
055 0114	DAGTERIOTIOS				
OFF CHA	RACTERISTICS				
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 1.0 \text{ mA}, I_{\rm B} = 0$	150		V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C = 100  \mu A,  I_E = 0$	160		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = 10  \mu A,  I_C = 0$	5.0		V
I <sub>CBO</sub>	Collector Cutoff Current	$V_{CB} = 120 \text{ V}, I_E = 0$ $V_{CB} = 120 \text{ V}, I_E = 0, T_A = 100^{\circ}\text{C}$		50 50	nA μA
I <sub>EBO</sub>	Emitter Cutoff Current	$V_{EB} = 3.0 \text{ V}, I_{C} = 0$		50	nA
LIFE	DO Guiterit Gairi	$I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}$	60	240	
ON CHAH	ACTERISTICS*  DC Current Gain	$I_{C} = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$	50		
		$I_C = 50 \text{ mA}, V_{CE} = 5.0 \text{ V}$	50	0.0	.,,
$V_{\text{CE(sat)}}$	Collector-Emitter Saturation Voltage	$I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA}$ $I_C = 50 \text{ mA}, I_B = 5.0 \text{ mA}$		0.2 0.5	V V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 1.0 mA I <sub>C</sub> = 50 mA, I <sub>B</sub> = 5.0 mA		1.0	V
SMALL S	IGNAL CHARACTERISTICS  Current Gain - Bandwidth Product	$I_{C} = 10 \text{ mA}, V_{CE} = 10 \text{ V},$	100	300	MHz
		f = 100 MHz			
C <sub>obo</sub>	Output Capacitance	$V_{CB} = 10 \text{ V}, I_{E} = 0,$ f = 1.0 MHz		6.0	pF
NF	Noise Figure	$\begin{split} I_C &= 250 \; \mu \text{A}, \; V_{CE} = 5.0 \; \text{V}, \\ R_S &= 1.0 \; \text{k} \Omega, \\ f &= 10 \; \text{Hz to } 15.7 \; \text{kHz} \end{split}$		8.0	dB

<sup>\*</sup>Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%

**NOTE:** All voltages (V) and currents (A) are negative polarity for PNP transistors.

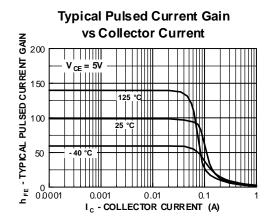
### **Spice Model**

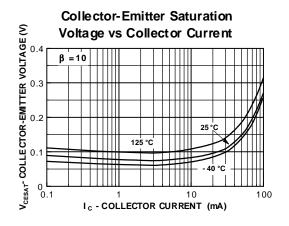
 $PNP \ (Is=21.48f \ Xti=3 \ Eg=1.11 \ Vaf=100 \ Bf=132.1 \ Ne=1.375 \ Is=21.48f \ Ikf=.1848 \ Xtb=1.5 \ Br=3.661 \ Nc=2 \ Isc=0 \ Ikr=0 \ Rc=1.6 \ Cjc=17.63p \ Mjc=.5312 \ Vjc=.75 \ Fc=.5 \ Cje=73.39p \ Mje=.3777 \ Vje=.75 \ Tr=1.476n \ Tf=641.9p \ Itf=0 \ Vtf=0 \ Xtf=0 \ Rb=10)$ 

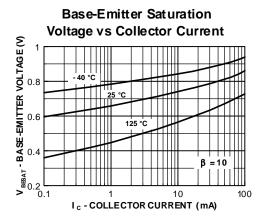
### **PNP General Purpose Amplifier**

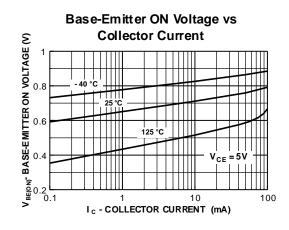
(continued)

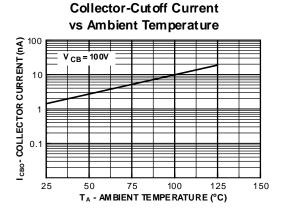
### **Typical Characteristics**

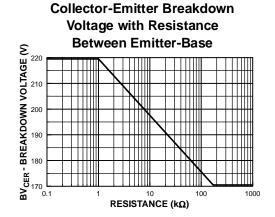








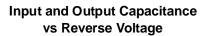


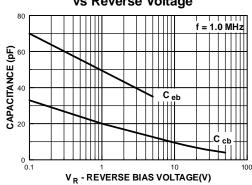


## **PNP General Purpose Amplifier**

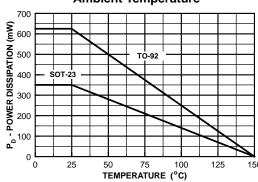
(continued)

## **Typical Characteristics** (continued)





### Power Dissipation vs Ambient Temperature

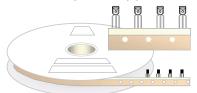


### **TO-92 Tape and Reel Data** FAIRCHILD SEMICONDUCTOR TM **TO-92 Packaging** Configuration: Figure 1.0 **TAPE and REEL OPTION** FSCINT Label sample See Fig 2.0 for various Reeling Styles CBVK//418019 **FSCINT** Label 5 Reels per Intermediate Box Customized F63TNR Label sample Label F63TNR LOT: CBVK741B019 QTY: 2000 FSID: PN222N Customized QTY1: QTY2: 375mm x 267mm x 375mm Intermediate Box TO-92 TNR/AMMO PACKING INFROMATION **AMMO PACK OPTION** See Fig 3.0 for 2 Ammo Packing Style Quantity EOL code **Pack Options** 2,000 D26Z Е 2,000 D27Z Ammo М 2,000 D74Z 2,000 D75Z **FSCINT** Unit weight = 0.22 gm Reel weight with components = 1.04 kg Ammo weight with components = 1.02 kg Max quantity per intermediate box = 10,000 units Label 5 Ammo boxes per Intermediate Box 327mm x 158mm x 135mm Immediate Box Customized F63TNR Customized Label Label 333mm x 231mm x 183mm Intermediate Box (TO-92) BULK PACKING INFORMATION **BULK OPTION** See Bulk Packing DESCRIPTION QUANTITY Information table J18Z TO-18 OPTION STD 2.0 K / BOX Anti-static Bubble Sheets TO-5 OPTION STD NO LEAD CLIP 1.5 K / BOX J05Z **FSCINT Label** NO EOL TO-92 STANDARD STRAIGHT FOR: PKG 92, NO LEADCLIP 2.0 K / BOX 94 (NON PROELECTRON SERIES), 96 TO-92 STANDARD STRAIGHT FOR: PKG 94 (PROELECTRON SERIES BCXXX, BFXXX, BSRXXX), 97, 98 L34Z NO LEADCLIP 2.0 K / BOX 2000 units per 114mm x 102mm x 51mm EO70 box for std option Immediate Box 5 EO70 boxes per intermediate Box 530mm x 130mm x 83mm Customized Intermediate box Label FSCINT Label 10,000 units maximum per intermediate box for std option

### TO-92 Tape and Reel Data, continued

# **TO-92 Reeling Style Configuration:** Figure 2.0

### Machine Option "A" (H)

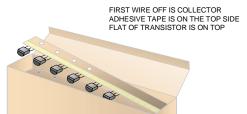


Style "A", D26Z, D70Z (s/h)

# Machine Option "E" (J)

Style "E", D27Z, D71Z (s/h)

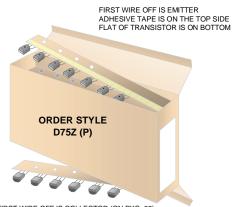
# **TO-92 Radial Ammo Packaging Configuration:** Figure 3.0



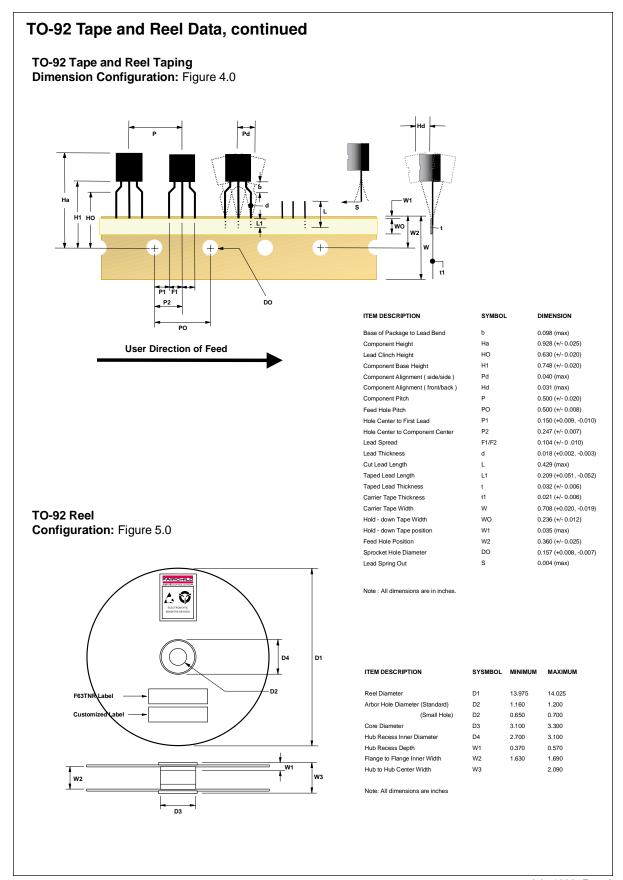
FIRST WIRE OFF IS EMITTER (ON PKG. 92) ADHESIVE TAPE IS ON BOTTOM SIDE FLAT OF TRANSISTOR IS ON BOTTOM

ORDER STYLE

D74Z (M)



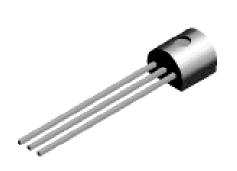
FIRST WIRE OFF IS COLLECTOR (ON PKG. 92) ADHESIVE TAPE IS ON BOTTOM SIDE FLAT OF TRANSISTOR IS ON TOP

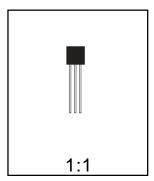


## **TO-92 Package Dimensions**



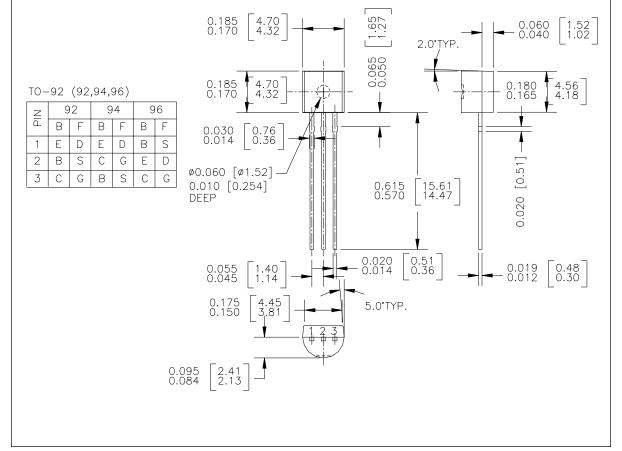
# TO-92 (FS PKG Code 92, 94, 96)

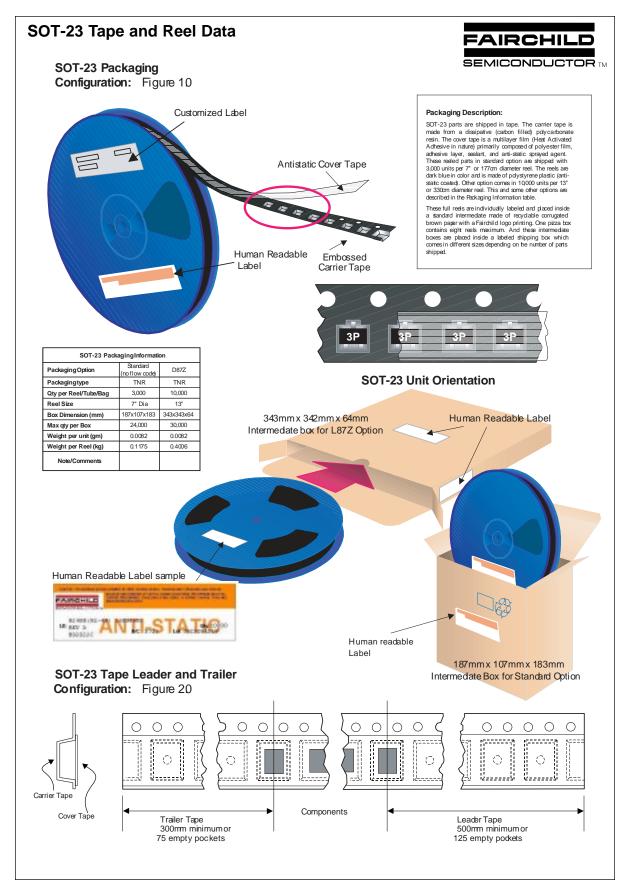




Scale 1:1 on letter size paper
Dimensions shown below are in:
inches [millimeters]

Part Weight per unit (gram): 0.1977

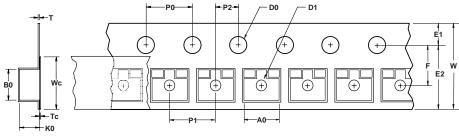




## SOT-23 Tape and Reel Data, continued

### **SOT-23 Embossed Carrier Tape**

Configuration: Figure 3.0



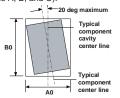
User	Direction	of Feed	

	Dimensions are in millimeter													
Pkg type	Α0	В0	w	D0	D1	E1	E2	F	P1	P0	K0	Т	Wc	Тс
<b>SOT-23</b> (8mm)	3.15 +/-0.10	2.77 +/-0.10	8.0 +/-0.3	1.55 +/-0.05	1.125 +/-0.125	1.75 +/-0.10	6.25 min	3.50 +/-0.05	4.0 +/-0.1	4.0 +/-0.1	1.30 +/-0.10	0.228 +/-0.013	5.2 +/-0.3	0.06 +/-0.02

Notes: A0, B0, and K0 dimensions are determined with respect to the EIA/Jedec RS-481 rotational and lateral movement requirements (see sketches A, B, and C).



Sketch A (Side or Front Sectional View)
Component Rotation

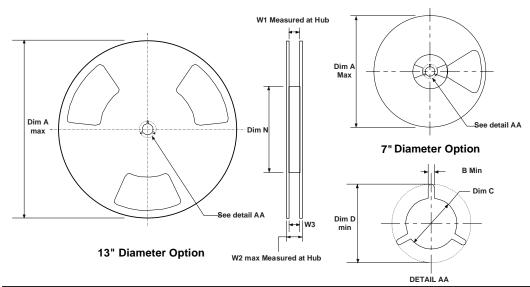


Sketch B (Top View)
Component Rotation



Sketch C (Top View)
Component lateral movement

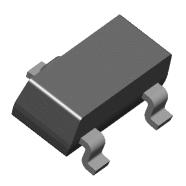
### SOT-23 Reel Configuration: Figure 4.0

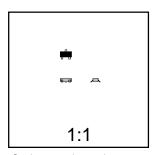


	Dimensions are in inches and millimeters										
Tape Size Reel Option Dim A Dim B Dim C Dim D Dim N Dim W1 Dim W2 Dim W3 (LSL-US								Dim W3 (LSL-USL)			
8mm	7" Dia	7.00 177.8	0.059 1.5	512 +0.020/-0.008 13 +0.5/-0.2	0.795 20.2	2.165 55	0.331 +0.059/-0.000 8.4 +1.5/0	0.567 14.4	0.311 - 0.429 7.9 - 10.9		
8mm	13" Dia	13.00 330	0.059 1.5	512 +0.020/-0.008 13 +0.5/-0.2	0.795 20.2	4.00 100	0.331 +0.059/-0.000 8.4 +1.5/0	0.567 14.4	0.311 - 0.429 7.9 - 10.9		



# SOT-23 (FS PKG Code 49)

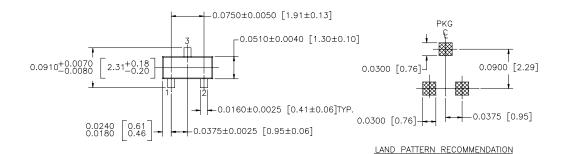


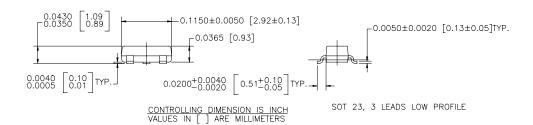


Scale 1:1 on letter size paper

Dimensions shown below are in: inches [millimeters]

Part Weight per unit (gram): 0.0082





NOTE: UNLESS OTHERWISE SPECIFIED

- 1. STANDARD LEAD FINISH 150 MICROINCHES / 3.81 MICROMETERS MINIMUM TIN / LEAD (SOLDER) ON ALLOY 42
- 2. REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE G, DATED JUL 1993

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DOME™ ISOPLANAR™ Quiet Series™

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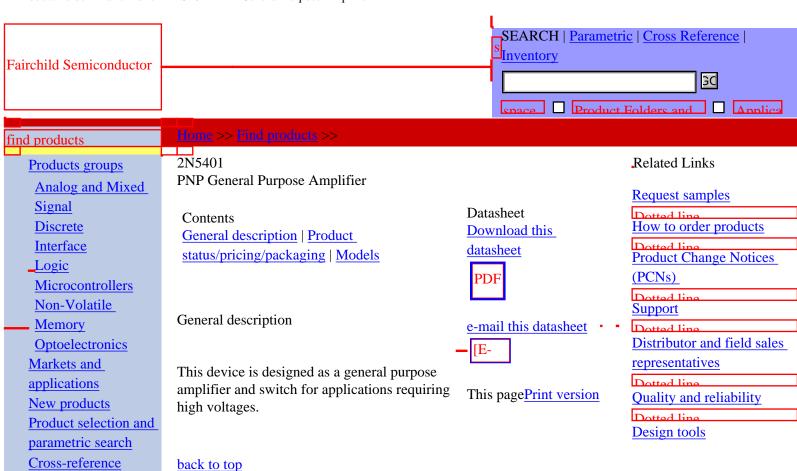
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- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

### PRODUCT STATUS DEFINITIONS

### **Definition of Terms**

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.



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Product status/pricing/packaging

Product	Product status	Pricing*	Inventory check & ordering	Package type	Leads	Package marking	Packing method
2N5401	Not recommended for new designs	\$0.102	Purchase	TO-92	3	\$Y&Z&3 2N 5401	BULK
2N5401CTA	Full Production	\$0.065	Purchase	<u>TO-92</u>	3	N/A	TAPE REEL
2N5401TA	Full Production	\$0.065	Purchase	<u>TO-92</u>	3	N/A	TAPE REEL
2N5401RA	Not recommended for new designs	\$0.102	Purchase	TO-92	3	\$Y&Z&3 2N 5401	TAPE REEL
2N5401BU	Full Production	\$0.065	Purchase	<u>TO-92</u>	3	N/A	BULK
2N5401RM	Not recommended for new designs	\$0.102	Purchase	TO-92	3	\$Y&Z&3 2N 5401	AMMO
2N5401TF	Full Production	\$0.065	Purchase	<u>TO-92</u>	3	N/A	TAPE REEL

<sup>\*</sup> Fairchild 1,000 piece Budgetary Pricing

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### Models

Package & leads	Condition	Temperature range	Software version	Revision date
PSPICE				
TO-92-3	Electrical	25°C	N/A	N/A

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